

ACPM-9313

LTE Band 13/14 MIPI APT PA

2.0 mm × 2.5 mm

Power Amplifier Module

Product Brief



Description

The ACPM-9313 is a fully matched 10-pin surface mount power amplifier module developed for LTE Band 13 and Band 14. The 2 mm × 2.5 mm form-factor package is self contained, and it incorporates 50-ohm input and output matching networks.

The ACPM-9313 features CoolPAM circuit technology that supports two power modes—low and high. The CoolPAM is a stage bypass technology that enhances PAE (power added efficiency) at low power range. The stage bypass feature enhances PAE further at low output range, and it enables the PA to have exceptionally low quiescent current. Without a DC-DC converter, it dramatically saves average current consumption, extends the talk time of mobiles, and prolongs the battery life. It can be used with the APT (average power tracking) operation to reduce the power consumption when VCC1 and VCC2 are connected to a DC-DC converter externally, which adjusts the VCC1 and VCC2 voltage according to the output power level.

The power amplifier is manufactured on an advanced InGaP HBT (hetero-junction bipolar transistor) MMIC (microwave monolithic integrated circuit) technology that offers state-of-the-art reliability, temperature stability, and ruggedness.

Features

- Thin package (0.82 mm typical)
- Excellent linearity in APT mode
- MIPI RFFE interface
- Two-mode power
- Quiescent current control for high power mode and low power mode
- Ten-pin surface mounting package
- Internal 50-ohm matching networks for both RF input and output
- Separate drive and output VCC supplies
- Green – Lead-free and RoHS compliant

Applications

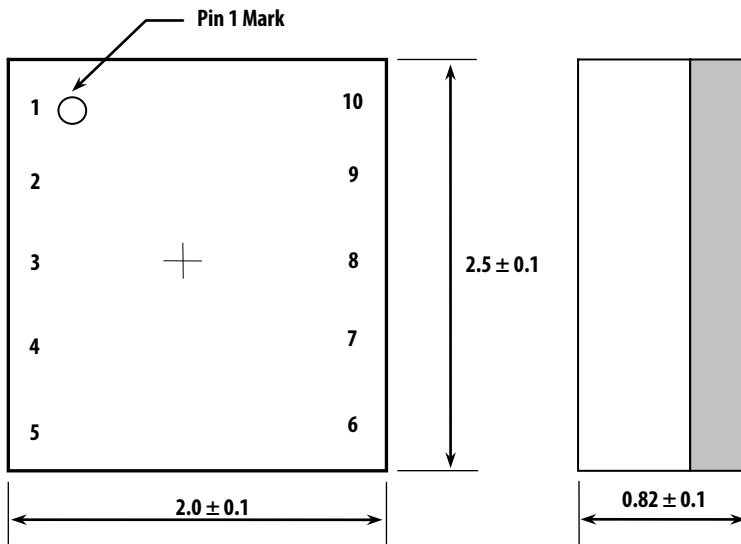
- LTE Band 13
- LTE Band 14

Ordering Information

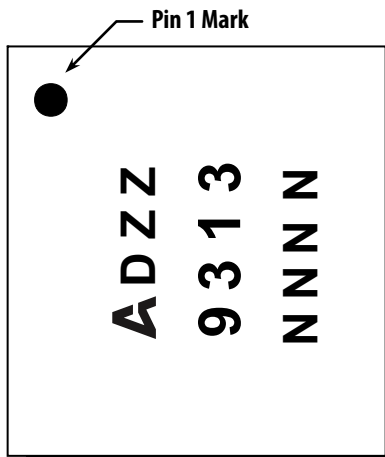
Part Number	Number of Devices	Container
ACPM-9313-TR1	1,000	178 mm (7 in.) tape/reel

Package Dimensions

The dimensions are in millimeters.



Marking Specification



D – Date Code
ZZ – Assembly Lot Identification
9313 – Device Code

Pin Description

Pin #	Name	Description
1	VCC1	DC supply voltage, connect the first RF stage collector to which APT is applied (0.5V~3.5V)
2	RFIN	RF input
3	VBAT	DC supply voltage, connect to the bias circuitry with a fixed voltage (higher than 3.2V)
4	VIO	RFFE enable
5	SDATA	RFFE data
6	SCLK	RFFE clock
7	GND	Ground
8	SEL	RFFE duplicate device select
9	RFOUT	RF output
10	VCC2	DC supply voltage, connect to the second RF stage collector to which APT is applied (0.5V~3.5V)

For product information and a complete list of distributors, please go to our web site:

www.avagotech.com

Avago, Avago Technologies, and the A logo are trademarks of Avago Technologies in the United States and other countries. All other brand and product names may be trademarks of their respective companies.

Data subject to change. Copyright © 2015 Avago Technologies. All Rights Reserved.

AV02-4848EN – 2015-03-24

